

# Joon-Seok Kim

## List of Publications by Year in descending order

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19  
papers

2,396  
citations

623734

14  
h-index

940533

16  
g-index

19  
all docs

19  
docs citations

19  
times ranked

4956  
citing authors

#	ARTICLE	IF	CITATIONS
1	A review on mechanics and mechanical properties of 2D materials—Graphene and beyond. <i>Extreme Mechanics Letters</i> , 2017, 13, 42-77.	4.1	920
2	Flexible Black Phosphorus Ambipolar Transistors, Circuits and AM Demodulator. <i>Nano Letters</i> , 2015, 15, 1883-1890.	9.1	394
3	Toward air-stable multilayer phosphorene thin-films and transistors. <i>Scientific Reports</i> , 2015, 5, 8989.	3.3	344
4	Long-Term Stability and Reliability of Black Phosphorus Field-Effect Transistors. <i>ACS Nano</i> , 2016, 10, 9543-9549.	14.6	158
5	Origin of superconductivity in the Weyl semimetal $WT_2e_2$ under pressure. <i>Physical Review B</i> , 2016, 94, .	3.2	91
6	Large-Area Dry Transfer of Single-Crystalline Epitaxial Bismuth Thin Films. <i>Nano Letters</i> , 2016, 16, 6931-6938.	9.1	87
7	Thermal Oxidation of $WSe_2$ Nanosheets Adhered on $SiO_2/Si$ Substrates. <i>Nano Letters</i> , 2015, 15, 4979-4984.	9.1	84
8	Characterization and sonochemical synthesis of black phosphorus from red phosphorus. <i>2D Materials</i> , 2016, 3, 014007.	4.4	57
9	Highly-stable black phosphorus field-effect transistors with low density of oxide traps. <i>Npj 2D Materials and Applications</i> , 2017, 1, .	7.9	57
10	Experimental evidence of exciton capture by mid-gap defects in CVD grown monolayer $MoSe_2$ . <i>Npj 2D Materials and Applications</i> , 2017, 1, .	7.9	56
11	Pressure-Induced Charge Transfer Doping of Monolayer Graphene/ $MoS_2$ Heterostructure. <i>Small</i> , 2016, 12, 4063-4069.	10.0	45
12	Towards band structure and band offset engineering of monolayer $Mo(1-x)W_xS_2$ via Strain. <i>2D Materials</i> , 2018, 5, 015008.	4.4	28
13	Laser-assisted oxidation of multi-layer tungsten diselenide nanosheets. <i>Applied Physics Letters</i> , 2016, 108, .	3.3	25
14	High pressure Raman study of layered $Mo_{0.5}W_{0.5}S_2$ ternary compound. <i>2D Materials</i> , 2016, 3, 025003.	4.4	20
15	Large area chemical vapor deposition growth of monolayer $MoSe_2$ and its controlled sulfurization to $MoS_2$ . <i>Journal of Materials Research</i> , 2016, 31, 917-922.	2.6	14
16	Structural, vibrational, and electronic topological transitions of $Bi_{1.5}Sb_{0.5}Te_{1.8}Se_{1.2}$ under pressure. <i>Journal of Applied Physics</i> , 2018, 123, .	2.5	14
17	(Invited) silicene and phosphorene: Progress on the intriguing case of buckled atomic sheets. , 2015, , .		1
18	Reliability of black phosphorus field-effect transistors with respect to bias-temperature and hot-carrier stress. , 2017, , .		1

#	ARTICLE	IF	CITATIONS
19	Accurate mapping of oxide traps in highly-stable black phosphorus FETs. , 2017, , .		0